# Engineering Development Model

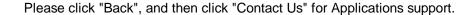
## **RF Transformer**

## JTX1-ED11400/1

Impedance Ratio: 1

### **Important Note**

This model has been designed, built and tested in our engineering department. Performance data represents model capability. At present it is a non-catalog model. On request, we can supply a final specification sheet, part number and price/delivery information.





**CASE STYLE: 99-01-519** 

ELECTRICAL SPECIFICATIONS 50Ω @ +25°C					
Parameter		Min.	Тур.	Max.	Units
Frequency		.3		200	MHz
Insertion Loss *	3 dB Bandwidth		.3-200		MHz
	2 dB Bandwidth		2-125		MHz
	1 dB Bandwidth		10-70		MHz

#### Note:

<sup>\*</sup> Insertion Loss is referenced to mid-band loss, 0.18 dB typ.

MAXIMUM RATINGS			
Operating Temperature	-20°C to 85°C		
Storage Temperature	-55°C to 100°C		
RF Power	0.25W		
DC Current	30 mA		

PIN CONNECTIONS				
PRIMARY DOT	4			
PRIMARY	6			
SECONDARY DOT	1			
SECONDARY	3			
SECONDARY CT	2			
NOT USED	5			

